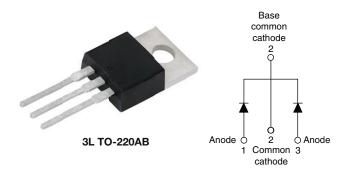
**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 2 x 30 A



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PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 30 A				
V <sub>R</sub>	150 V				
V <sub>F</sub> at I <sub>F</sub>	0.72 V				
I <sub>RM</sub> max.	20 mA at 125 °C				
T <sub>J</sub> max.	175 °C				
E <sub>AS</sub>	0.4 mJ				
Package	3L TO-220AB				
Circuit configuration	Common cathode				

### **FEATURES**

- 175 °C T<sub>J</sub> operation
- · Low forward voltage drop
- · High frequency operation



HALOGEN

FREE

- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## DESCRIPTION

The VS-60CTQ150... center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS VALUES UNI					
I <sub>F(AV)</sub>	Rectangular waveform	60	А			
V <sub>RRM</sub>		150	V			
IFSM	$t_p = 5 \ \mu s \ sine$	710	А			
V <sub>F</sub>	30 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (typical, per leg)	0.69	V			
TJ	Range	-55 to +175	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-60CTQ150-M3	UNITS			
Maximum DC reverse voltage	VR	150	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	130	V			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS			
Maximum average forward per leg		50 % duty avala at T <sub>2</sub> = 137 °C	rectangular waveform	30			
current, see fig. 5 per device	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 137 °C, rectangular waveform		60			
Maximum peak one cycle non-repetitive		5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and	710	A		
surge current per leg, see fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	with rated V <sub>RRM</sub> applied	270			
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 0.9 A, L = 1 mH		0.4	mJ		
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zer Frequency limited by $T_J$ maxim		0.9	А		

Revision: 15-Aug-17



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		30 A	T <sub>1</sub> = 25 °C	0.83	0.88			
Maximum forward voltage drop per leg See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	60 A	1j=25 0	0.98	1.09	V		
	VFM (*)	30 A	T 105 %O	0.67	0.72			
		60 A	T <sub>J</sub> = 125 °C	0.82	0.87			
Maximum reverse leakage current per leg	I <sub>RM</sub>	$T_J = 25 \ ^{\circ}C$	$V_{\rm B}$ = Rated $V_{\rm B}$	7	75	μA		
See fig. 2		T <sub>J</sub> = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	7.2	20	mA		
Typical junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		-	650	pF		
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body			7.5	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		-	10 000	V/µs		

#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,\,duty\,cycle$  < 2  $\,\%$ 

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	•	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C	
Maximum thermal resistance,	per leg	R <sub>thJC</sub>	DC operation See fig. 4	1.2		
junction to case	junction to case per package		DC operation	0.6	°C/W	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.25	0,11	
Approximate weight				6	g	
Approximate weight				0.21	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
maximum				12 (10)	(lbf ⋅ in)	
Marking device			Case style 3 L TO-220AB	60CT	Q150	



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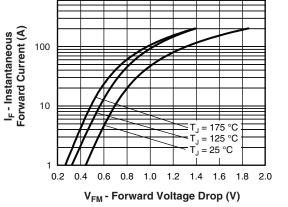


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

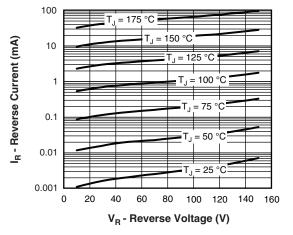


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

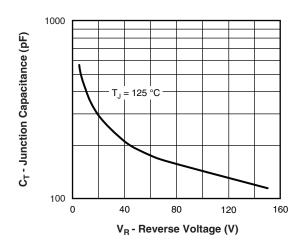


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

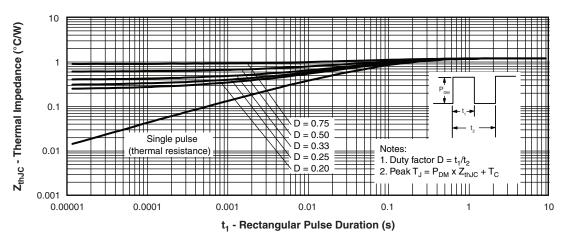
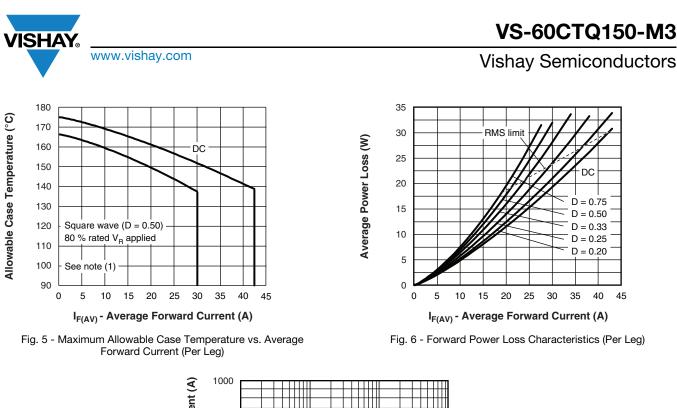


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

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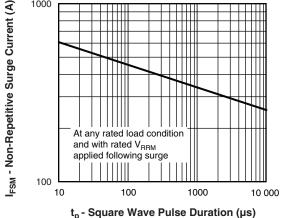


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

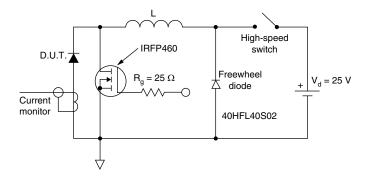


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);

 $Pd_{REV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = 80 % rated  $V_R$ 

Revision: 15-Aug-17

4

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## **ORDERING INFORMATION TABLE**

Device code	VS-	60	С	т	Q	150	-M3
	1	2	3	4	5	6	7
1	-	Vishay	Semico	nductor	s produo	ct	
2	-	Curren	t rating	(60 = 60	A)		
3	-	Circuit	configui	ration			
		C = co	mmon c	athode			
4	-	Packag	je				
		T = TO	-220				
5	-	Schott	ky "Q" se	eries			
6	-	Voltage	e rating	(150 = 1	50 V)		
7	-	Enviro	nmental	digit			
		-M3 = ł	nalogen	-free, Ro	HS-con	npliant,	and ter

ORDERING INFORMATION (Example)						
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-60CTQ150-M3	50	1000	Antistatic plastic tube			

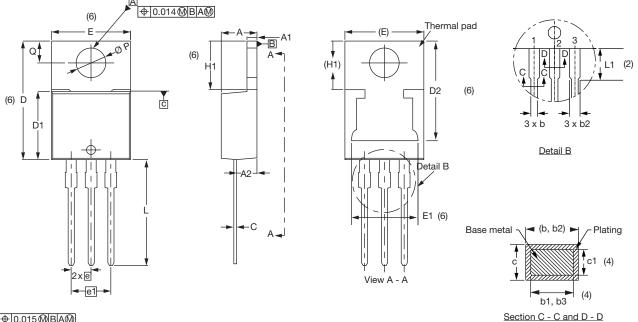
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96154					
Part marking information	www.vishay.com/doc?95028				



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# **3L TO-220AB**

### **DIMENSIONS** in millimeters and inches



⊕0.015@BA@





SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

_		
Conforms to JEDEC <sup>®</sup>	outline	<b>TO-220AB</b>

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
Ш	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

#### Notes

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

- <sup>(4)</sup> Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2

Revision: 13-Jun-2019

 $<sup>^{(1)}\,</sup>$  Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(3)</sup> Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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